MLCC Tin/Lead Termination "B" (LD Series)

COG (NPO) - General Specifications





AVX Corporation will support those customers for commercial and military Multilayer Ceramic Capacitors with a termination consisting of 5% minimum lead. This termination is indicated by the use of a "B" in the 12th position of the AVX Catalog Part Number. This fulfills AVX's commitment to providing a full range of products to our customers. AVX has provided in the following pages a full range of values that we are currently offering in this special "B" termination. Please contact the factory if you require additional information on our MLCC Tin/Lead Termination "B" products.

Not RoHS Compliant

PART NUMBER (SEE PAGE 4 FOR COMPLETE PART NUMBER EXPLANATION)

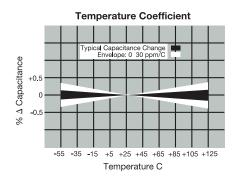
LD05	<u>5</u>	<u>A</u>	101	_	<u>A</u>	<u>B</u>	2	<u>A</u>
Size LD02 - 0402 LD03 - 0603 LD04 - 0504* LD05 - 0805 LD06 - 1206 LD10 - 1210 LD12 - 1812 LD13 - 1825 LD14 - 2225 LD14 - 2225	Voltage 6.3V = 6 10V = Z 16V = Y 25V = 3 35V = D 50V = 5 100V = 1 200V = 2 500V = 7	Dielectric COG (NPO) = A X7R = C X5R = D X8R = F	Capacitance Code (In pF) 2 Sig. Digits + Number of Zeros	Capacitance Tolerance $B = \pm .10 \text{ pF} (<10 \text{ pF})$ $C = \pm .25 \text{ pF} (<10 \text{ pF})$ $D = \pm .50 \text{ pF} (<10 \text{ pF})$ $F = \pm 1\% (\ge 10 \text{ pF})$ $G = \pm 2\% (\ge 10 \text{ pF})$ $J = \pm 5\%$ $K = \pm 10\%$ $M = \pm 20\%$	Failure Rate A = Not Applicable 4 = Automotive	Terminations B = 5% min lead X = FLEXITERM® with 5% min lead** **X7R only	Packaging 2 = 7" Reel 4 = 13" Reel Contact Factory For Multiples*	Special Code A = Std. Product

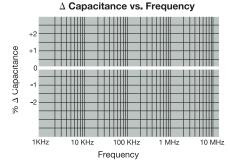
 $M = \pm 20\%$

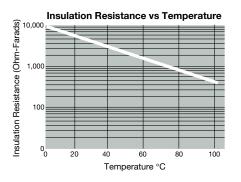
*LD04 has the same CV ranges as LD03.

See FLEXITERM® section for CV options

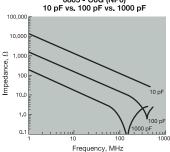
NOTE: Contact factory for availability of Tolerance Options for Specific Part Numbers. Contact factory for non-specified capacitance values.

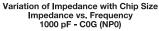


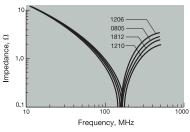




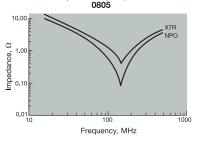
Variation of Impedance with Cap Value Impedance vs. Frequency 0805 - COG (NP0) 10 pF vs. 100 pF vs. 1000 pF







Variation of Impedance with Ceramic Formulation Impedance vs. Frequency 1000 pF - C0G (NP0) vs X7R





The Important Information/Disclaimer is incorporated in the catalog where these specifications came from or available online at www.avx.com/disclaimer/ by reference and should be reviewed in full before placing any order.





Parame	ter/Test	NP0 Specification Limits	Measuring (Conditions			
Operating Tem	perature Range	-55°C to +125°C	Temperature C				
Сарас	itance	Within specified tolerance	Freq.: 1.0 MHz ± 10%	% for cap ≤ 1000 pF			
()	<30 pF: Q≥ 400+20 x Cap Value ≥30 pF: Q≥ 1000	1.0 kHz ± 10% fo Voltage: 1.0	r cap > 1000 pF			
Insulation	Resistance	100,000ΜΩ or 1000ΜΩ - μF, whichever is less	Charge device with 60 ± 5 secs @ roor				
Dielectric	Strength	No breakdown or visual defects	Charge device with 250 1-5 seconds, w/charge limited to 50 Note: Charge device with for 500V	and discharge current mA (max) n 150% of rated voltage			
	Appearance	No defects	Deflectio				
Resistance to Flexure	Capacitance Variation	±5% or ±.5 pF, whichever is greater	Test Time: 3	30 seconds 7 1mm/sec			
Stresses	Q	Meets Initial Values (As Above)					
	Insulation Resistance	≥ Initial Value x 0.3	90 r	mm —			
Solder	ability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic for 5.0 ± 0.5				
	Appearance	No defects, <25% leaching of either end terminal					
	Capacitance Variation	≤ ±2.5% or ±.25 pF, whichever is greater					
Resistance to Solder Heat	Q	Meets Initial Values (As Above)	Dip device in eutectic s seconds. Store at room				
Solder Heat	Insulation Resistance	Meets Initial Values (As Above)	hours before measuring	g electrical properties.			
	Dielectric Strength	Meets Initial Values (As Above)					
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes			
	Capacitance Variation	≤ ±2.5% or ±.25 pF, whichever is greater	Step 2: Room Temp	≤ 3 minutes			
Thermal Shock	Q	Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes			
	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes			
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles 24 hours at roor				
	Appearance	No visual defects					
	Capacitance Variation	≤ ±3.0% or ± .3 pF, whichever is greater	Charge device with twice				
Load Life	Q	≥ 30 pF: Q≥ 350 ≥10 pF, <30 pF: Q≥ 275 +5C/2 <10 pF: Q≥ 200 +10C	chamber set at for 1000 hou Remove from test chamb	rs (+48, -0).			
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	temperature f before me	for 24 hours			
	Dielectric Strength	Meets Initial Values (As Above)					
	Appearance	No visual defects					
	Capacitance Variation	≤ ±5.0% or ± .5 pF, whichever is greater	Store in a test chamber s	et at 85°C + 2°C/ 85% +			
Load Humidity	Q	≥ 30 pF: Q≥ 350 ≥10 pF, <30 pF: Q≥ 275 +5C/2 <10 pF: Q≥ 200 +10C	Store in a test chamber set at 85°C ± 2°C/ 85% ± 5% relative humidity for 1000 hours (+48, -0) with rated voltage applied. Remove from chamber and stabilize at room temperature for 24 ± 2 hours before measuring.				
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)					
	Dielectric Strength	Meets Initial Values (As Above)					

COG (NPO) - Capacitance Range



PREFERRED SIZES ARE SHADED

		LD02							□ I D05										
SIZE											LD05	-			-	LD0			
Solder			eflow/Wa All Paper				v/Wave Paper				flow/Wav					Reflow/ aper/Em			
Packag	mm		.00 ± 0.1				± 0.15				.01 ± 0.20					3.20 ± (
(L) Length	(in.)		040 ± 0.0				± 0.006)				79 ± 0.00					(0.126 ±			
W) Width	mm		.50 ± 0.1				± 0.15				.25 ± 0.20					1.60 ± (
	(in.) mm		020 ± 0.0 0.25 ± 0.1				± 0.006) ± 0.15				049 ± 0.00 .50 ± 0.2					0.50 ± (0.063)			
(t) Terminal	(in.)		010 ± 0.0				± 0.006)				0.00 ± 0.00				((0.020 ±			
	WVDC	16	25	50	16	25	50	100	16	25	50	100	200	16	25	50	100	200	500
Cap (pF)	0.5 1.0	C	C	C	G G	G G	G G	G G	J	J	J	J	J	J	J	J	J	J J	J
(pi)	1.2	C	Č	Č	Ğ	Ğ	Ğ	Ğ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ
	1.5	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	1.8	C C	C	C	G G	G G	G G	G G	J	J	J	J	J	J	J	J	J	J	J
	2.7	Ċ	Č	Č	Ğ	G	G	Ğ	J	J	Ĵ	J	Ĵ	J	J	J	Ĵ	J	J
	3.3	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	3.9 4.7	C	C	C	G G	G G	G G	G G	J	J	J	J	J	J	J	J	J	J J	J
	5.6	C	C	C	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	6.8	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	8.2 10	C	C	C	G G	G	G	G G	J	J	J	J	J	J	J	J	J	J	J
	10	C	C	C	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	15	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	18 22	C	C	C	G G	G G	G G	G G	J	J	J	J	J	J	J	J	J	J	J
	27	C	C	C	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	33	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	39 47	С	С	C	G G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	56	C	C	C	G	G	G	G G	J	J	J	J	J	J	J	J	J	J	J
	68	С	С	С	G	Ğ	G	G	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ
	82	C	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	100 120	C C	C	C	G G	G G	G G	G G	J	J	J	J	J	J	J	J	J	J	J
	150	Č	Č	Č	Ğ	Ğ	Ğ	Ğ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ
	180	С	С	С	G	G	G	G	J	J	J	J.	J	J	J	J	J	J.	٦.
	220 270	C C	C	C	G G	G G	G G	G G	J	J	J	J	J M	J	J	J	J	J	M M
	330	C	C	C	G	G	G	G	J	J	J	J	M	J	J	J	J	J	M
	390	С	С	С	G	G	G	G	J	J	J	J	М	J	J	J	J	J	М
	470 560	С	С	С	G G	G	G G		J	J	J	J	M M	J	J	J	J	J	M
	680				G	G	Ğ		J	J	J	J	101	J	J	Ĵ	J	J	P
	820				G	G	G		J	J	J	J		J	J	J	J	М	
	1000 1200				G	G G	G		J	J	J	J		J	J	J	J	QQ	
	1500						1		J	J	J			J	J	Ĵ	M	Q	
	1800								J	J	J			J	J	М	М		
	2200 2700								J	J	N N			J	J	M M	P P		
	3300								J	J	.,			J	J	M	Р		
	3900								J	J				J	J	М	Р		
	4700 5600								J	J				J	J	M M	Р		
	6800													M	M	IVI			
	8200													М	М				
Cap (pF)	0.010 0.012													M	M				
(Pi)	0.012			-		I IAI	I												
	0.018			كيا-		W-	× ⁻												
	0.022 0.027		1))	ĴT												
	0.033		ا (\	ر ا														
	0.039																		
	0.047		ļ		t		_												
	0.068 0.082				ĺ	1	I												
	0.1																		
	WVDC	16	25	50	16	25	50	100	16	25	50	100	200	16	25	50	100	200	500
	SIZE		LD02			LD	03				LD05					LD0	ס		

Letter	Α	С	Е	G	J	K	М	N	Р	Q	Х	Υ	Z
Max.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
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C0G (NP0) - Capacitance Range



PREFERRED SIZES ARE SHADED

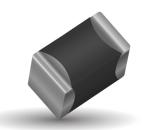
SIZ	E			LD10					LD12					LD13				LD14	
Solde	rina		F	Reflow Or	nly			R	eflow On	ly			F	Reflow O	nly			Reflow Only	
Packa				er/Embo				Al	l Emboss	ed			Al	II Embos	sed			All Embossed	
(L) Length	mm			3.20 + 0.2					1.50 ± 0.3					4.50 ± 0.				5.72 ± 0.25	
(L) Length	(in.)			.126 ± 0.0					177 ± 0.0					177 ± 0.				(0.225 ± 0.010))
W) Width	mm (in.)			2.50 ± 0.2 .098 ± 0.0					3.20 ± 0.20 126 ± 0.00				(0.	6.40 ± 0. .252 ± 0.	40 016)		(6.35 ± 0.25 (0.250 ± 0.010))
(t) Terminal	mm			0.50 ± 0.2	25				0.61 ± 0.3	6			(0.61 ± 0.	36			0.64 ± 0.39	
(t) Terrimon	(in.) WVDC	25		.020 ± 0.0		F00	25		024 ± 0.0		I 500	50	(0.	.024 ± 0.		200		0.025 ± 0.015	
Сар	0.5	25	50	100	200	500	25	50	100	200	500	50	_	100		200	50	100	200
(pF)	1.0																		
" /	1.2				i i				İ							ĺ			
	1.5																		
	1.8 2.2																	-	E IN
	2.2																اسما		₩>
	3.3																<u> </u>)) [T
	3.9																		<u></u>
	4.7			1	+			\perp					_		\perp		_ `	$\overline{}$	20
	5.6 6.8																	4	
	8.2																	' '	İ
	10					J							\neg		\neg				
	12					J													
	15 18					J													
	22					J													
	27					Ĵ													
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	39 47					J													
	56				+ +	J		+ +											
	68					Ĵ													
	82					J													
	100					J													
	120 150					J													
	180					J													
	220				i i	J													
	270				\perp	J													
	330 390					J													
	470					M M													
	560	J	J	J	J	М													
	680	J	J	J	J	М													
	820	J	<u>J</u>	J	J	М	1/	1/	1/	1/			_						
	1000 1200	J	J	J	J M	M M	K K	K K	K K	K K	M M	M M		M M		M M	M M	M M	P P
	1500	J	J	J	M	M	K	K	K	K	M	M		M		M	M	M	P
	1800	J	J	J	М		K	K	K	K	М	М		М		М	М	М	Р
	2200	J	J	J	Q		K	K	K	K	P	M		М		M	М	М	P
	2700 3300	J	J J	J	Q		K	K	K	P P	Q	M		M M		M M	M M	M M	P P
	3900	J	J	M			K	K	K	P	Q	M		M		M	M	M	P
	4700	J	Ĵ	М			K	К	K	P	Q	М		М		М	M	М	P
	5600	J	J				K	K	M	P	Х	M		M		M	M	М	Р
	6800 8200	J	J				K K	K M	M M	Χ		M M		M M		М	M M	M M	P P
Сар	0.010	J	J		+ +		K	M	M			M		M			M	M	P
(pF)	0.012	J	J				K	М				М		М		I	М	М	Р
	0.015			ļ	1		M	M				M		M			M	M	Y
	0.018 0.022						M M	M M				P P		М			M M	M Y	Y Y
	0.022						M	M				P					P	Y	Y
	0.033						М	М				Р					Р		
	0.039						М	М				P					P		
,	0.047			-	+		M	M				Р					P P		
	0.082						M	M									Q		
	0.1																Q		
	WVDC	25	50	100	200	500	25	50	100	200	500	50		100		200	50	100	200
SIZ	E			LD10					LD12					LD13				LD14	
		1 -		- 1		1	1	14									1 -		
Letter	Α	C		E	G	J	$\overline{}$	K 1.00	M		N 10	P 1.50	1.		X	Υ 0.54	Z 270	H	
Max. Thickness	0.33	0.50		0.71	0.90	0.9		1.02	1.27		.40	1.52	1.7		2.29	2.54	2.79		
HICKIESS	(0.013)	(0.02	.4) (0.028)	(0.035)	(0.03	3/)	(0.040)	(0.050) (0.	055)	(0.060)	(0.0	170)	(0.090)	(0.100)) (0.110)		

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X8R - General Specifications





AVX Corporation will support those customers for commercial and military Multilayer Ceramic Capacitors with a termination consisting of 5% minimum lead. This termination is indicated by the use of a "B" in the 12th position of the AVX Catalog Part Number. This fulfills AVX's commitment to providing a full range of products to our customers. AVX has provided in the following pages a full range of values that we are currently offering in this special "B" termination. Please contact the factory if you require additional information on our MLCC Tin/Lead Termination "B" products.

Not RoHS Compliant

PART NUMBER (SEE PAGE 4 FOR COMPLETE PART NUMBER EXPLANATION)

LD05	<u>5</u>	F	101	<u>J</u>	<u>A</u>	<u>B</u>	<u>2</u>	<u>A</u>
Size LD02 - 0402 LD03 - 0603 LD04 - 0504* LD05 - 0805 LD06 - 1206 LD10 - 1210 LD12 - 1812 LD13 - 1825 LD14 - 2225 LD20 - 2220	Voltage 6.3V = 6 10V = Z 16V = Y 25V = 3 35V = D 50V = 5 100V = 1 200V = 2 500V = 7	Dielectric X8R = F	Capacitance Code (In pF) 2 Sig. Digits + Number of Zeros	Capacitance Tolerance $B = \pm .10 \text{ pF} (<10 \text{ pF})$ $C = \pm .25 \text{ pF} (<10 \text{ pF})$ $D = \pm .50 \text{ pF} (<10 \text{ pF})$ $F = \pm 1\% (\ge 10 \text{ pF})$ $G = \pm 2\% (\ge 10 \text{ pF})$ $J = \pm 5\%$ $K = \pm 10\%$ $M = \pm 20\%$	Failure Rate A = Not Applicable	Terminations B = 5% min lead X = FLEXITERM® with 5% min lead** **X7R only	Packaging 2 = 7" Reel 4 = 13" Reel Contact Factory For Multiples*	Special Code A = Std. Product

LD04 has the same CV ranges as LD03.

See FLEXITERM® section for CV options

NOTE: Contact factory for availability of Tolerance Options for Specific Part Numbers.

Contact factory for non-specified capacitance values.





Parame	ter/Test	X8R Specification Limits	Measuring (Conditions
Operating Tem	perature Range	-55°C to +150°C	Temperature C	ycle Chamber
Capac	itance	Within specified tolerance	From : 1.0 k	d I = 1 100/
Dissipati	on Factor	≤ 2.5% for ≥ 50V DC rating ≤ 3.5% for 25V DC and 16V DC rating	Freq.: 1.0 k Voltage: 1.0	
Insulation	Resistance	100,000ΜΩ or 1000ΜΩ - μF, whichever is less	Charge device with 120 ± 5 secs @ roo	
Dielectric	: Strength	No breakdown or visual defects	Charge device with 250 1-5 seconds, w/charge limited to 50 Note: Charge device with for 500V	and discharge current mA (max) n 150% of rated voltage
	Appearance	No defects	Deflectio	n: 2mm
Resistance to	Capacitance Variation	≤ ±12%	Test Time: 3	
Flexure Stresses	Dissipation Factor	Meets Initial Values (As Above)		
	Insulation Resistance	≥ Initial Value x 0.3	90 r	mm
Solder	rability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic for 5.0 ± 0.9	
	Appearance	No defects, <25% leaching of either end terminal		
	Capacitance Variation	≤ ±7.5%		
Resistance to Solder Heat	Dissipation Factor	Meets Initial Values (As Above)	Dip device in eutectic s seconds. Store at room	temperature for 24 ± 2
	Insulation Resistance	Meets Initial Values (As Above)	hours before measuring	g electrical properties.
	Dielectric Strength	Meets Initial Values (As Above)		
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes
	Capacitance Variation	≤ ±7.5%	Step 2: Room Temp	≤ 3 minutes
Thermal Shock	Dissipation Factor	Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes
	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles 24 ± 2 hours at ro	
	Appearance	No visual defects		
	Capacitance Variation	≤ ±12.5%	Charge device with 1.5 r	
Load Life	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	for 1000 hou	
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from test chamb temperature for 24 ± 2 h	
	Dielectric Strength	Meets Initial Values (As Above)		
	Appearance	No visual defects		
	Capacitance Variation	≤ ±12.5%	Store in a test chamber s 5% relative humidi	ty for 1000 hours
Load Humidity	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	(+48, -0) with rated	d voltage applied.
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from chamber temperature an 24 ± 2 hours bef	d humidity for
	Dielectric Strength	Meets Initial Values (As Above)	Z4 I Z HOURS DEI	ore measuring.



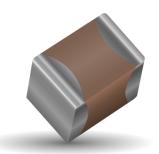


	SIZE	LD	03	LD	05	LD	06
	WVDC	25V	50V	25V	50V	25V	50V
271	Cap 270	G	G				
331		G	G	J	J		
471	470	G	G	J	J		
681	680	G	G	J	J		
102	1000	G	G	J	J	J	J
152	1500	G	G	J	J	J	J
182	1800	G	G	J	J	J	J
222	2200	G	G	J	J	J	J
272	2700	G	G	J	J	J	J
332	3300	G	G	J	J	J	J
392	3900	G	G	J	J	J	J
472		G	G	J	J	J	J
562	5600	G	G	J	J	J	J
682		G	G	J	J	J	J
822		G	G	J	J	J	J
103		G	G	J	J	J	J
123	0.012	G	G	J	J	J	J
153	0.015	G	G	J	J	J	J
183	0.018	G	G	J	J	J	J
223	0.022	G	G	J	J	J	J
273	0.027	G	G	J	J	J	J
333	0.033	G	G	J	J	J	J
393	0.039	G	G	J	J	J	J
473		G	G	J	J	J	J
563		G		N	N	M	М
683	0.068	G		N	N	М	М
823	0.082			N	N	М	М
104	0.1			N	N	М	М
124	0.12			N	N	М	М
154	0.15			N	N	М	М
184	0.18			N		M	М
224	0.22			N		М	М
274	0.27					M	М
334	0.33					M	М
394	0.39					М	
474	0.47					M	
684	0.68						
824	0.82						
105	1						
	WVDC	25V	50V	25V	50V	25V	50V
	SIZE	LD	03	LD	05	LD	06

Letter	Α	С	Е	G	J	K	М	N	Р	Q	Х	Υ	Z
Max.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
			PAPER						EMBC	SSED			

X7R - General Specifications





AVX Corporation will support those customers for commercial and military Multilayer Ceramic Capacitors with a termination consisting of 5% minimum lead. This termination is indicated by the use of a "B" in the 12th position of the AVX Catalog Part Number. This fulfills AVX's commitment to providing a full range of products to our customers. AVX has provided in the following pages a full range of values that we are currently offering in this special "B" termination. Please contact the factory if you require additional information on our MLCC Tin/Lead Termination "B" products.

Not RoHS Compliant

PART NUMBER (SEE PAGE 4 FOR COMPLETE PART NUMBER EXPLANATION)

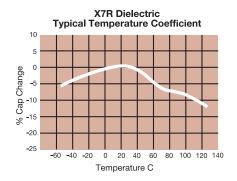
LD05	5	<u>c</u>	101	J	<u>A</u>	<u>B</u>	2	<u>A</u>
Size LD03 - 0603 LD04 - 0504* LD05 - 0805 LD06 - 1206 LD10 - 1210 LD12 - 1812 LD13 - 1825 LD14 - 2225 LD20 - 2220	Voltage 6.3V = 6 10V = Z 16V = Y 25V = 3 35V = D 50V = 5 100V = 1 200V = 2 500V = 7	Dielectric X7R = C	Capacitance Code (In pF) 2 Sig. Digits + Number of Zeros	Capacitance Tolerance B = \pm .10 pF (<10pF) C = \pm .25 pF (<10pF) D = \pm .50 pF (<10pF) F = \pm 1% (\geq 10 pF) G = \pm 2% (\geq 10 pF) J = \pm 5% K = \pm 10% M = \pm 20%	Failure Rate A = Not Applicable	Terminations B = 5% min lead X = FLEXITERM® with 5% min lead** **X7R only	Packaging 2 = 7" Reel 4 = 13" Reel Contact Factory For Multiples*	Special Code A = Std. Product

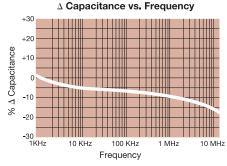
^{*}LD04 has the same CV ranges as LD03.

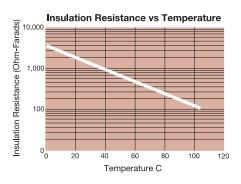
See FLEXITERM® section for CV options

NOTE: Contact factory for availability of Tolerance Options for Specific Part Numbers.

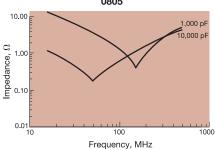
Contact factory for non-specified capacitance values.

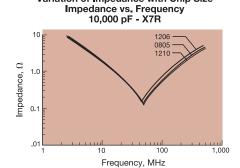






Variation of Impedance with Cap Value Impedance vs. Frequency 1,000 pF vs. 10,000 pF - X7R 0805





Variation of Impedance with Chip Size

Impedance vs. Frequency
100,000 pF - X7R

10
1206
0805
1210

1210
100 100 1,000
Frequency, MHz

Variation of Impedance with Chip Size





Parame	ter/Test	X7R Specification Limits	Measuring (Conditions
Operating Tem	perature Range	-55°C to +125°C	Temperature C	ycle Chamber
Capac	itance	Within specified tolerance		
Dissipati	on Factor	≤ 10% for ≥ 50V DC rating ≤ 12.5% for 25V DC rating ≤ 12.5% for 25V and 16V DC rating ≤ 12.5% for ≤ 10V DC rating	Freq.: 1.0 k Voltage: 1.0'	
Insulation	Resistance	100,000MΩ or 1000MΩ - μF, whichever is less	Charge device with 120 ± 5 secs @ roo	
Dielectric	: Strength	No breakdown or visual defects	Charge device with 250 1-5 seconds, w/charge limited to 50 Note: Charge device with for 500V	and discharge current mA (max) n 150% of rated voltage
	Appearance	No defects	Deflectio	n: 2mm
Resistance to	Capacitance Variation	≤ ±12%	Test Time: 3	
Flexure Stresses	Dissipation Factor	Meets Initial Values (As Above)	V	
	Insulation Resistance	≥ Initial Value x 0.3	90 r	nm —
Solder	rability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic for 5.0 ± 0.5	
	Appearance	No defects, <25% leaching of either end terminal		
	Capacitance Variation	≤ ±7.5%		
Resistance to Solder Heat	Dissipation Factor	Meets Initial Values (As Above)	Dip device in eutectic s seconds. Store at room	temperature for 24 ± 2
	Insulation Resistance	Meets Initial Values (As Above)	hours before measuring	g electrical properties.
	Dielectric Strength	Meets Initial Values (As Above)		
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes
	Capacitance Variation	≤ ±7.5%	Step 2: Room Temp	≤ 3 minutes
Thermal Shock	Dissipation Factor	Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes
	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles 24 ± 2 hours at ro	
	Appearance	No visual defects		
	Capacitance Variation	≤ ±12.5%	Charge device with 1.5 r	
Load Life	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	for 1000 hou	
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from test chamb temperature for 24 ± 2 h	
	Dielectric Strength	Meets Initial Values (As Above)		
	Appearance	No visual defects		
	Capacitance Variation	≤ ±12.5%	Store in a test chamber s 5% relative humidi	
Load Humidity	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	(+48, -0) with rated	l voltage applied.
Humbulty	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from chamber temperature an	d humidity for
	Dielectric Strength	Meets Initial Values (As Above)	24 ± 2 hours bef	ore measuring.





PREFERRED SIZES ARE SHADED

						LD03				LD05						LD06										
SIZE			LD02														-									
Solderin			low/W					low/W							low/W							Reflow				
Packagi (L) Length	mm	1.0	II Pap 00 ± 0	.10			1.0	II Pap 60 ± 0	.15					2.	r/Emb 01 ± 0.	.20						3.20 ±	0.20			
(L) Length	(in.)		40 ± 0					63 ± 0							79 ± 0.						(0.126 ±		8)		
W) Width	mm (in.)		50 ± 0 20 ± 0					81 ± 0 32 ± 0							25 ± 0. 49 ± 0.						((1.60 ± ± 0.063		8)		
(A) T	mm		25 ± 0					35 ± 0							50 ± 0.							0.50 ±		-,		
(t) Terminal	(in.)	$(0.0)^{\circ}$	10 ± 0	.006)			(0.0)	14 ± 0	.006)			(0.020 ± 0.010)								((0.020 ±	0.01	0)			
WVDC		16	25	50	6.3	10	16	25	50	100	200	0 6.3 10 16 25 50 100 200				200	6.3	10	16	25	50	100	200	500		
Сар	100																									
(pF)	150																									
(1-)	220			С					İ																	
	330			С					G	G	G		J	J	J	J	J	J								K
	470			C					G	G	G		Ĵ	J	J	J	J	J								K
	680			C					G	G	Ğ		Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ								K
	1000			C					G	G	G		J	J	J	J	J	J								K
	1500			C					G	G			Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ		J	J	J	J	J	J	M
	2200			C			GGG													J	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	M
	3300		С	C				G]]]]]]]					J		J	J	J	J	J	J	М				
	4700		c	c														J		J	Ĵ	J	Ĵ	Ĵ	J	М
	6800	С	c																				Р			
Сар	0.010	C	C						G	G			J	J	J	J	J	J		J	J	J	J	J	J	P
(μF)	0.015	C		1				G	G				Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ		J	Ĵ	Ĵ	Ĵ	Ĵ	М	
(P.)	0.022	C						G	G				Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	N		J	Ĵ	Ĵ	Ĵ	Ĵ	М	
	0.033	C						G	G				J	J	J	J	N			J	J	J	J	J	М	
	0.047	-					G	G	G				J	J	J	Ĵ	N			J	J	J	J	J	М	
	0.068						G	G	G				Ĵ	J	J	Ĵ	N			J	J	J	J	Ĵ	Р	
	0.10		C*			G	G	G	G				J	J	J	J	N			J	J	J	J	P	P	
	0.15				G	G							Ĵ	Ĵ	Ĵ	Ň	N			J	Ĵ	Ĵ	Ĵ	Q	·	
	0.22				G	G							Ĵ	Ĵ	N	N	N			J	Ĵ	Ĵ	Ĵ	Q		
	0.33												N	N	N	N	N			J	J	М	P	Q		\vdash
	0.47							J*					N	N	N	N	N			M	М	М	Р	Q		
	0.68												N	N	N					М	М	Q	Q	Q		
	1.0					J*	J*						N	N	N*					М	М	Q	Q	Q		\vdash
	1.5																			P	Q	Q				
	2.2				J*	ĺ									P*					0	Q	Q				
	3.3																			-	1	_				
	4.7												P*	P*						0*	0*	0*				
	10											P*	P							Q*	Q*	Q				
	22																		Q*							
	47																									
	100																									L
	WVDC	16	25	50	6.3					6.3	10	16	25	50	100	200	0 6.3 10 16 25 50 100 200 500				500					
	SIZE		LD02			LD03							LD05							LD	06					

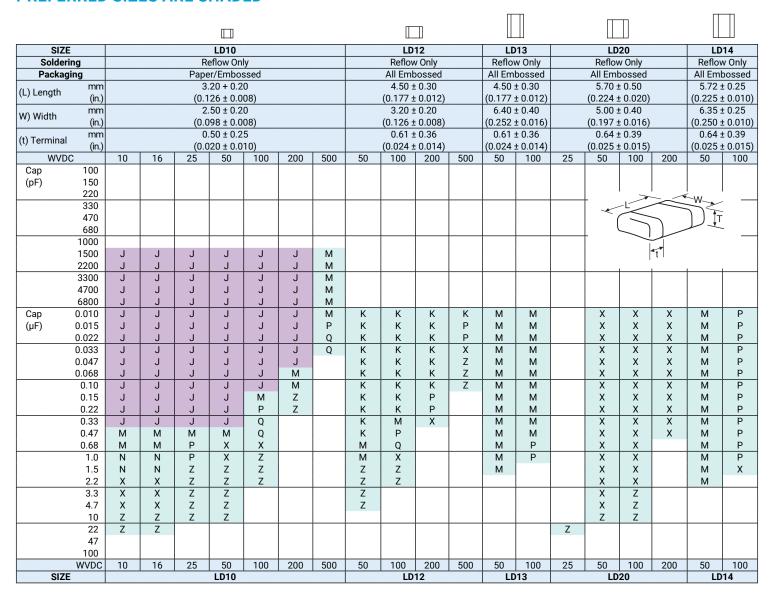
Letter	Α	С	Е	G	J	K	М	N	Р	Q	Х	Υ	Z
Max.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013)	(0.022) (0.028) (0.0			(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.100)	(0.110)	
	PAPER								EMBC	SSED			



X7R - Capacitance Range



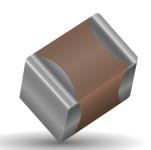
PREFERRED SIZES ARE SHADED



Letter	Α	С	E	G	J	K	М	N	Р	Q	Χ	Υ	Z
Max.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
			PAPER						EMBC	SSED			

X5R - General Specifications





AVX Corporation will support those customers for commercial and military Multilayer Ceramic Capacitors with a termination consisting of 5% minimum lead. This termination is indicated by the use of a "B" in the 12th position of the AVX Catalog Part Number. This fulfills AVX's commitment to providing a full range of products to our customers. AVX has provided in the following pages a full range of values that we are currently offering in this special "B" termination. Please contact the factory if you require additional information on our MLCC Tin/Lead Termination "B" products.

Not RoHS Compliant

PART NUMBER (SEE PAGE 4 FOR COMPLETE PART NUMBER EXPLANATION)

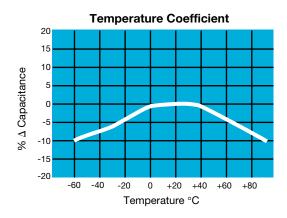
LD05	<u>5</u>	D	101	J	A	В	2	A
Size LD02 - 0402 LD03 - 0603 LD04 - 0504* LD05 - 0805 LD06 - 1206 LD10 - 1210 LD12 - 1812 LD13 - 1825 LD14 - 2225 LD20 - 2220	Voltage 6.3V = 6 10V = Z 16V = Y 25V = 3 35V = D 50V = 5 100V = 1 200V = 2 500V = 7	Dielectric X5R = D	Capacitance Code (In pF) 2 Sig. Digits + Number of Zeros	Capacitance Tolerance $B = \pm .10 \text{ pF} (<10 \text{ pF})$ $C = \pm .25 \text{ pF} (<10 \text{ pF})$ $D = \pm .50 \text{ pF} (<10 \text{ pF})$ $F = \pm 1\% (\ge 10 \text{ pF})$ $G = \pm 2\% (\ge 10 \text{ pF})$ $J = \pm 5\%$ $K = \pm 10\%$ $M = \pm 20\%$	Failure Rate A = Not Applicable	Terminations B = 5% min lead X = FLEXITERM® with 5% min lead** **X7R only	Packaging 2 = 7" Reel 4 = 13" Reel Contact Factory For Multiples*	Special Code A = Std. Product

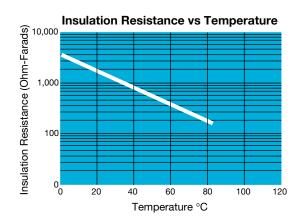
^{*}LD04 has the same CV ranges as LD03.

NOTE: Contact factory for availability of Tolerance Options for Specific Part Numbers. Contact factory for non-specified capacitance values.

See FLEXITERM® section for CV options

TYPICAL ELECTRICAL CHARACTERISTICS









Parame	ter/Test	X5R Specification Limits	Measuring (Conditions						
Operating Tem	perature Range	-55°C to +85°C	Temperature C	ycle Chamber						
Capac	itance	Within specified tolerance								
Dissipati	on Factor	≤ 2.5% for ≥ 50V DC rating ≤ 3.0% for 25V, 35V DC rating ≤ 12.5% Max. for 16V DC rating and lower Contact Factory for DF by PN	Freq.: 1.0 kHz ± 10% Voltage: 1.0Vrms ± .2V For Cap > 10 μF, 0.5Vrms @ 120Hz							
Insulation	Resistance	10,000MΩ or 500MΩ - μF, whichever is less	Charge device with rated voltage for 120 ± 5 secs @ room temp/humidity							
Dielectric	Strength	No breakdown or visual defects	Charge device with 250% of rated voltage for 1-5 seconds, w/charge and discharge current limited to 50 mA (max)							
	Appearance	No defects	Deflectio	n: 2mm						
Resistance to	Capacitance Variation	≤ ±12%	Test Time: 3	0 seconds 7 1mm/sec						
Flexure Stresses	Dissipation Factor	Meets Initial Values (As Above)								
	Insulation Resistance	≥ Initial Value x 0.3	90 r							
Solde	rability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic for 5.0 ± 0.5	solder at 230 ± 5°C 5 seconds						
	Appearance	No defects, <25% leaching of either end terminal								
	Capacitance Variation	≤ ±7.5%								
Resistance to Solder Heat	Dissipation Factor	Meets Initial Values (As Above)	Dip device in eutectic s seconds. Store at room	temperature for 24 ± 2						
	Insulation Resistance	Meets Initial Values (As Above)	hours before measuring	g electrical properties.						
	Dielectric Strength	Meets Initial Values (As Above)								
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes						
	Capacitance Variation	≤ ±7.5%	Step 2: Room Temp	≤ 3 minutes						
Thermal Shock	Dissipation Factor	Meets Initial Values (As Above)	Step 3: +85°C ± 2°	30 ± 3 minutes						
	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp ≤ 3 minutes							
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles 24 ± 2 hours at ro							
	Appearance	No visual defects		w . I li						
	Capacitance Variation	≤ ±12.5%	Charge device with 1.5 chamber set at 85°C = (+48, -0). Note: Contac	£ 2°C for 1000 hours						
Load Life	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	specification part number < 1.5X rate	pers that are tested at						
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from test chamb							
	Dielectric Strength	Meets Initial Values (As Above)	temperature for 24 ± 2 h	ours before measuring.						
	Appearance	No visual defects								
	Capacitance Variation	≤ ±12.5%	Store in a test chamber s 5% relative humidi	ty for 1000 hours						
Load Humidity	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	(+48, -0) with rated							
,	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from chamber temperature an 24 ± 2 hours bef	d humidity for						
	Dielectric Strength	Meets Initial Values (As Above)	2.2.10013 bei							





PREFERRED SIZES ARE SHADED

																	п	1																					
SIZ	E			L	D02					L	.D0	3					LD	05					LD	06						_D10)				LD'	12			
Solder	ring		F	eflo	w/W	ave			ı	Reflo	ow/\	Vave	9			Re	flow	/Wa	ve			R	eflow	/Wa	ve				Refle	ow/V	/ave								
Packag	ging			All	Pap	er				All	Pa	per			P	ape				ed	Paper/Embossed				Paper/Embossed														
(L) Length	mm				± 0.).15					.01 ±						3.20 ±				3.20 ± 0.20												
., -	(in.) mm				± 0.	004)		╄		0.8		0.00	6))79 ±				⊢		126 ±					(6 ± 0 0 ± 0)					_		
W) Width	(in.)					004)						0.00	6)				.23 <u>1</u>)49 <u>1</u>						063 ±					(8 ± 0)							
(t) Terminal	mm				± 0.					0.3	5 ± 0).15					.50 ±				İ).50 ±							0 ± 0							\neg		
WVD	(in.)					006)	1 50	1	(C 6.3			0.00		I =0	6.2		20 ±			LEO	6 2		020 :			ΙEΩ	1			0 ± 0			ΙEΩ	6.2	101	25 1			
Cap	100	4	0.3	10	10	23	30	4	0.3	10	10	23	33	30	0.3	10	10	23	33	30	0.3	10	10	23	33	30	4	0.3	10	10	23	33	30	0.3	10	23	30		
(pF)	150					ŀ																	ŀ														-		
(Pi)	220						С														l																-		
,	330						С		t												l											+		1	\vdash	- 1	\dashv		
	470						С				l										l									-1-	\nearrow	>	\leq	₹ -V	٧	_			
	680						С																					_	<		<	_		\int_{0}^{∞}	$\gamma \leq \gamma$	+			
	1000						С				İ	İ						İ											(_		7		L	ノĿ	Ψ.	1		
	1500						С																						•		◡	4							
	2200						С																								-	ا ا							
	3300						С																								ı								
	4700					С								G																						- 1			
	6800					С	_	_						G				<u> </u>	╄													<u> </u>			Ш				
Сар	0.010					С								G																									
(μF)	0.015					С						G	G	G									ļ																
	0.022			<u> </u>	С	С	-	-			-	G	G	G				-	+	N	H	-		<u> </u>								\vdash			\vdash				
	0.033				C	С						G	G	G						N																			
	0.047				C	0						G	G	G						N																			
	0.10			С	C	С		\vdash			┢	G	\vdash	G	\vdash			N	\vdash	N	Н	┢		┢								\vdash		-	\vdash	_	_		
	0.15					"						G		U	1			N	N	14	1		ŀ																
	0.22		C*								G	G						N	N N							Q													
	0.33										G	G						N	<u> </u>		t					_									H		_		
	0.47	C*	C*	ĺ							G		1					N						Q	Q								Х						
	0.68										G							N																					
	1.0	C*	C*	C*					G	G	G	J*					N	N		P*				Q	Q						Х	Х	Х			Ì			
	1.5																																						
	2.2	C*						G*	G*	J*	J*					N	N	N					Q	Q							Z	Х			Ш				
	3.3							J*	J*	J*	J*				N	N					Х	Х														I			
	4.7							J*	J*	J*					N	N	N*	N*			Х	Х	Х	Х						Q	Z								
	10			<u> </u>		<u> </u>	<u> </u>	K*		<u> </u>	<u> </u>	_	_		Р	Р	Р		\bot	<u> </u>	Х	Х	Х	Х			<u> </u>		X	Z	Z			<u> </u>	Ш	Z			
	22														P*						X	Х	Х	Х				Z	Z	Z	Z								
	47 100																				Х						Z*	Z*											
	WVDC	4	6.3	10	16	25	50	4	6.3	10	16	25	35	50	63	10	16	25	35	50	6.3	10	16	25	35	50		6.3	10	16	25	35	50	6.3	10	25	50		
	SIZE	-	10.3	_	D02	_	1 30	+	0.3	_	.DO	_	33	30	0.3	10	LD	_	[33	100	0.3	10	LD	_	133	100	+	10.3		LD10	_	133	100	0.3			50		
	SIZE				JUZ					_	יטע.						בט	00					LD	00						וטונ	_				בט	12	LD12		

Letter	Α	С	Е	G	J	K	М	N	Р	Q	Х	Υ	Z
Max.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
			PAPER						EMBC	SSED			

^{*}Optional Specifications - Contact factory

NOTE: Contact factory for non-specified capacitance values